

650V SiC Schottky Diode

FEATURES

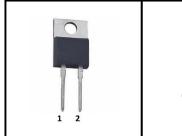
- Low Conduction and Swiitch Loss
- Positive Temperature Coefficient on VF
- Temperature Independent Switching Behavior
- Fast Reverse Recovery
- High Surge Current Capability
- Pb-free lead plating

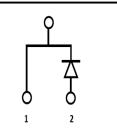
BENEFITS

- Higher System Efficiency
- Parallel Device Convenience
- High Temperature Application
- High Frequency Operation
- Hard Switching & High Reliability
- Environmental Protection

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)
- Solar/ Wind Renewable Energy
- Power Inverters
- Motor Drives







Device Marking and Package Information				
Device	Package	Marking		
C2S065H006B	TO-220-2L	C2S065H006B		

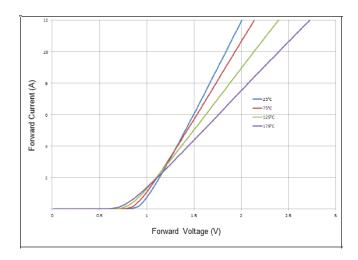
Absolute Maximum Ratings T _C = 25°C, unless otherwise noted					
Parameter	Symbol	Symbol Test Conditions		Unit	
Peak Repetitive Reverse Voltage	V_{RRM}	T _J = 25°C	650	V	
Peak Reverse Surge Voltage	V _{RSM}	T _J = 25°C	650	V	
DC Blocking Voltage	V _R	$T_{\rm J} = 25^{\rm o}{\rm C}$	650	V	
Continuous Forward Current	I _F	T _J ≤ 135°C	6	Α	
Repetitive Peak Forward Surge Current	I _{FRM}	$T_C = 25^{\circ}C$, $T_P = 8.3$ ms Half Sine Wave	60	Α	
Maximum Case Temperature	T _C		135	۰C	
Operating Junction and Storage Temperature	T _J , T _{stg}		-55~175	°C	

Thermal Resistance					
Parameter	Symbol	Value	Unit		
Thermal Resistance, Junction-to-Case	R _{thJC}	1.6	°C/W		



Specifications T _J = 25°C, unless otherwise noted							
Down of our	Symbol	Tool Conditions	Value		l lmi4		
Parameter		Test Conditions	Тур.	Max.	Unit		
Famurand Voltage	V _F	$I_F = 6A, T_J = 25^{\circ}C$	1.4	1.65	V		
Forward Voltage		I _F = 6A, T _J = 175°C	1.75	2.3	V		
Reverse Current	I _R	V _R =650V, T _J = 25°C	1	20	μΑ		
		V _R =650V, T _J = 175°C	5	100	μΑ		
Total Capacitive Charge	Q _C	$I_F = 6A$, di/dt =200A / μ s $V_R =650V$, $T_J = 25^{\circ}C$	18		nC		
Total Capacitance	С	$V_R = 0V, T_J = 25^{\circ}C, f = 1 MHz$	300		pF		
		V _R =200V, T _J = 25°C, , f =1 MHz	34				
		V _R =400V, T _J = 25°C, , f =1 MHz	18				





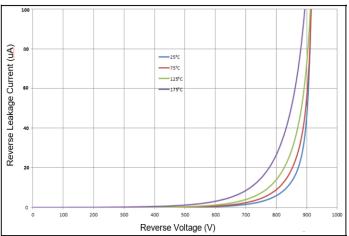
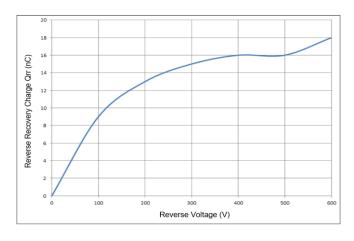


Fig. 1 Forward Characteristics

Fig. 2 Reverse Characteristics



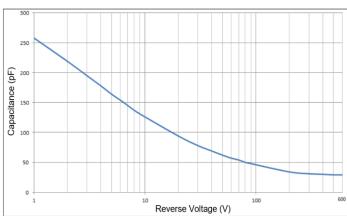


Fig. 3 Total Capacitance Charge vs. Reverse Voltage

Fig. 4 Total Capacitance vs. Reverse Voltage

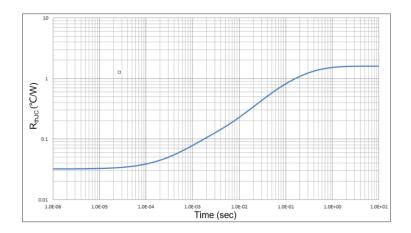
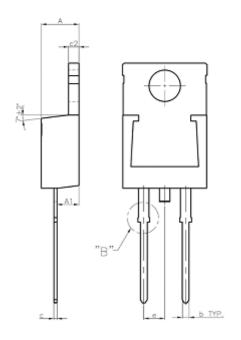


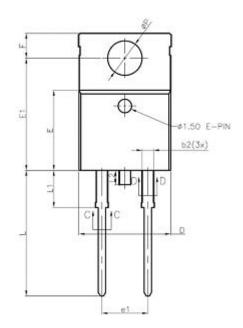
Fig. 5 Thermal characteristic curve

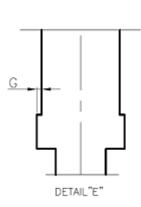


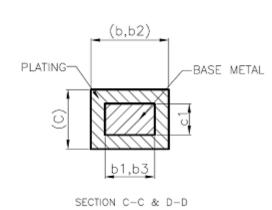
TO-220-2L



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
SIMBOLS	MIN	NOM	MAX	MIN	NOM	MAX
A	4.470		4.670	0.176		0.184
A1	2.520		2.820	0.099		0.111
Ь	0.710	0.813	0.910	0.028	0.032	0.036
b1	0.710		0.910	0.028		0.036
ь2	1.170	1.270	1.370	0.046	0.050	0.054
b3	1.170		1.370	0.046		0.054
С	0.279		0.483	0.011		0.019
c1	0.279		0.432	0.011		0.017
c2	1.170		1.370	0.046		0.054
D	10.010		10.310	0.394		0.406
E	8.763	8.890	9.017	0.345	0.350	0.355
E1	12.294	12.446	12.548	0.484	0.490	0.494
е		2.54 BSC			0.100 BSC	
e1	4.980		5.180	0.196		0.204
F	2.642	2.743	2.946	0.104	0.108	0.116
G	0.000		0.127	0.000		0.005
L	13.700		14.10	0.539		0.555
L1	4.04	4.11	4.19	0.159	0.162	0.165
L2			1.60			0.063
øP	3.790		3.890	0.149		0.153









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